



ZXTN25040DZ

40V NPN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

Features

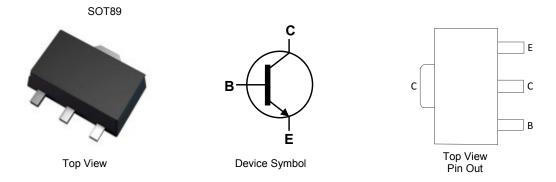
- BV_{CEO} > 40V
- I_C = 5.0A Continuous Current
- Low Saturation Voltage V_{CE(sat)} < 60mV @ 1A
- R_{sat} = 38mΩ for a Low Equivalent On-Resistance
- P_D = 2.4W Power Dissipation
- Complementary part number ZXTP25040DZ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.05 grams (Approximate)

Application

- Emergency lighting circuits
- Motor driving (including DC fans)
- Solenoid, relay and actuator drivers
- DC-DC modules
- Backlight inverters
- Power switches
- MOSFET gate drivers



Ordering Information (Note 4)

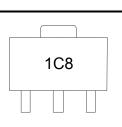
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTN25040DZTA	Standard	1C8	7	12	1,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



1C8 = Product Type Marking Code



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	130	V
Collector-Emitter Voltage (forward blocking)	V _{CEX}	130	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-collector voltage (reverse blocking)	V _{ECO}	6	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	5	А
Peak Pulse Collector Current	I _{CM}	10	А
Base current	IB	1	А

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

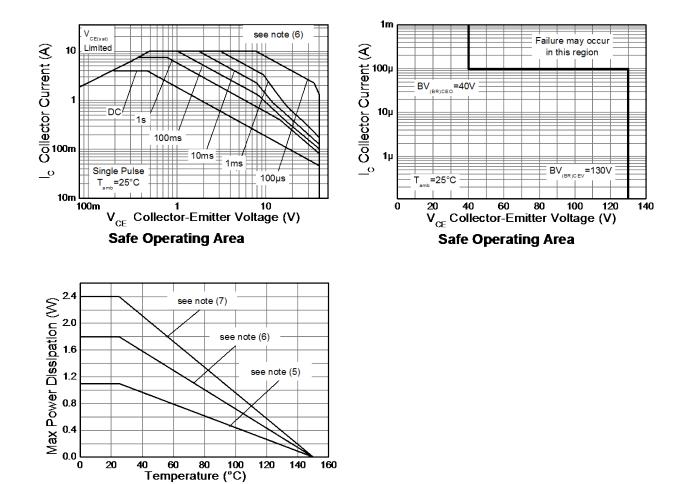
Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)		1.1		
Linear Derating Factor		8.8		
Power Dissipation (Note 6)		1.8		
Linear Derating Factor	PD	14.4	W	
Power Dissipation (Note 7)		2.4	mW/°C	
Linear Derating Factor		19.2		
Power Dissipation (Note 8)		4.46		
Linear Derating Factor		35.7		
Thermal Resistance, Junction to Ambient (Note 5)		117		
Thermal Resistance, Junction to Ambient (Note 6)	D	63	°C/W	
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JA}	51	°C/VV	
Thermal Resistance, Junction to Ambient (Note 8)		28		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	۵°	

5. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device Notes: 6. Same as note (5), except the device is mounted on 50mm x 50mm x 1.6mm single sided 2oz weight copper.
7. Same as note (5), except the device is mounted on 50mm x 50mm x 1.6mm single sided 2oz weight copper.
8. Same as note (5), except the device is measured at t<5 seconds.



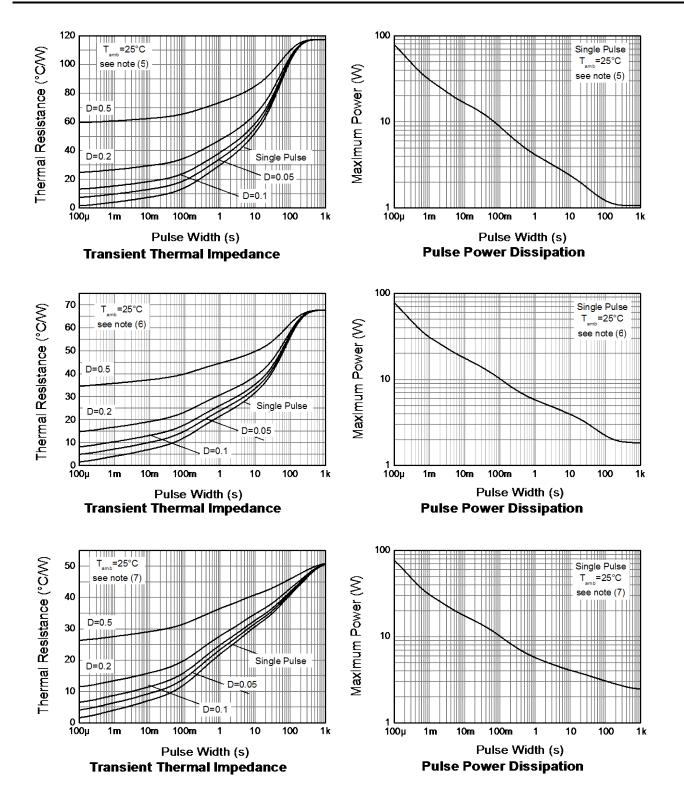
Thermal Characteristics and Derating Information

Derating Curve





Thermal Characteristics and Derating Information





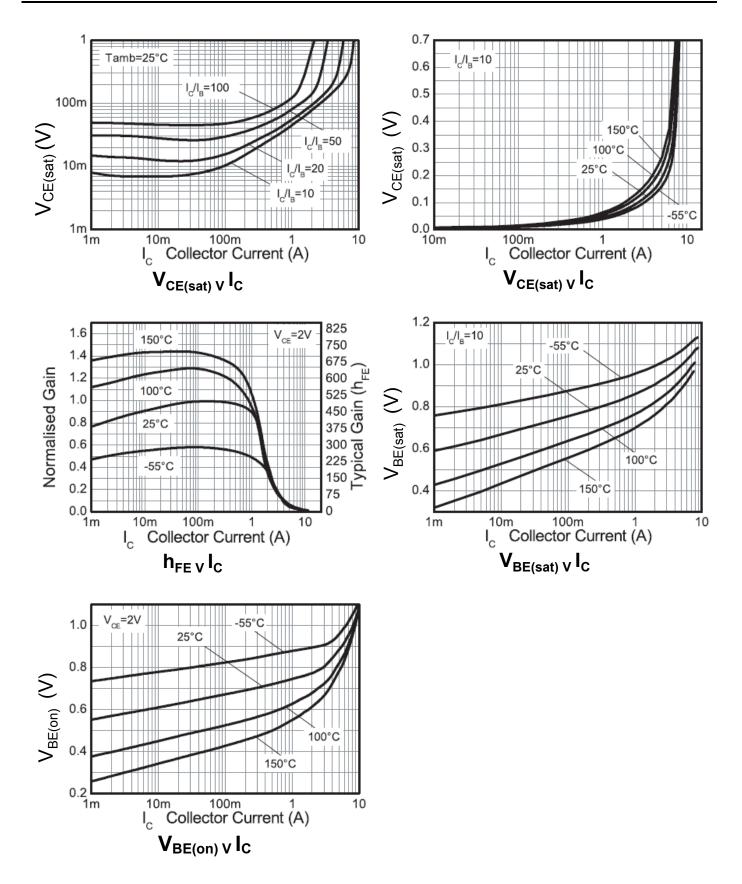
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	130	170		V	$I_{\rm C} = 100 \mu \text{A}$
Collector-Emitter Breakdown Voltage (forward blocking)	BVCBO	130	170	_	v	$I_{C} = 100 \mu A; R_{BE} \le 1 k \Omega \text{ or}$ -1V < V _{BE} < 0.25V
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	40	63	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.3	_	V	I _E = 100μA
Emitter-Collector Breakdown voltage (reverse blocking)	BV _{ECX}	6	7.4	_	V	$I_E = 100 \mu A, R_{BC} \le 1 k\Omega \text{ or}$ 0.25V > V _{BC} > -0.25V
Emitter-Collector Breakdown voltage	BV _{ECO}	6	7.4	_	V	I _E = 100μA
Collector Base Cut-Off Current	I _{CBO}	_	1	50 20	nA μA	V _{CB} = 100V V _{CB} = 100V, T _A = +100°C
Collector Emitter Cut-Off Current	I _{CEX} R ≤ 1kΩ	_	_	100	nA	V_{CE} = 100V; $R_{BE} \le 1k\Omega$ or -1V < $V_{BE} < 0.25V$
Emitter Cut-Off Current	I _{EBO}	_	1	50	nA	V _{EB} = 5.6V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	_	50 125 140 190	60 215 215 260	mV	$I_{C} = 1A, I_{B} = 100mA$ $I_{C} = 1A, I_{B} = 10mA$ $I_{C} = 2A, I_{B} = 40mA$ $I_{C} = 5A, I_{B} = 500mA$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	1000	1100	mV	I _C = 5A, I _B = 500mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	910	1000	mV	I _C = 5A, V _{CE} = 2V
DC Current Gain (Note 9)	h _{FE}	300 300 20 —	450 450 40 10	900 — — —	_	$I_{C} = 10mA, V_{CE} = 2V$ $I_{C} = 1A, V_{CE} = 2V$ $I_{C} = 5A, V_{CE} = 2V$ $I_{C} = 10A, V_{CE} = 2V$
Transitional frequency	f _T	_	190	_	MHz	I _C = 50mA, V _{CE} = 10V, f = 100MHz
Output Capacitance	C _{obo}	_	11.7	20	pF	V _{CB} = 10V, f = 1MHz
Delay time	t _d		64			
Rise time	tr	1	108			$V_{CC} = 10V$
Storage time	ts	1 —	428	—	ns	I _C = 1A, I _{B1} = -I _{B2} = 10mA
Fall time	t _f	1	130			$_{1B1} = -1B2 = 10111A$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

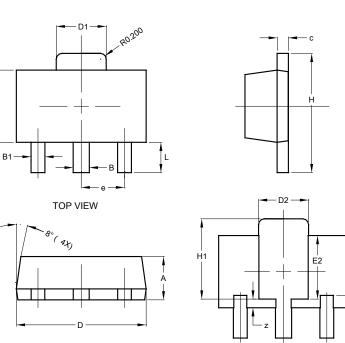




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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



BOTTOM VIEW

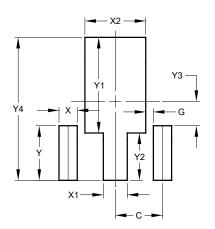
SOT89

L1

1	SOT89					
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
E	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
e	-	-	1.50			
н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
z	0.20	0.40	0.30			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Value Dimensions (in mm) С 1.500 G 0.244 Х 0.580 X1 0.760 X2 1.933 Y 1.730 Y1 3.030 Y2 1.500 **Y3** 0.770 Y4 4.530

SOT89



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